

HE8807SG/FL

GaAlAs Infrared Emitting Diodes

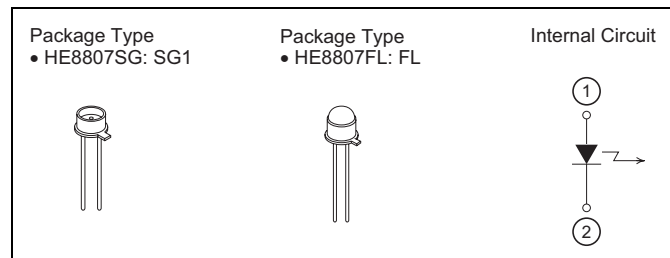
ODE-208-050 (Z)
Rev.0
Oct. 30, 2006

Description

The HE8807SG/FL are single heterojunction structure GaAlAs light emitting diodes with a wavelength of 880 nm.

Features

- High output, high efficiency
- Narrow spectral width
- Sharp radiation directivity (HE8807FL)
- Wide radiation directivity (HE8807SG)
- High reliability



Absolute Maximum Ratings

($T_C = 25^\circ\text{C}$)

Item	Symbol	Ratings	Unit
Forward current	I_F	200	mA
Reverse voltage	V_R	3	V
Operating temperature	T_{opr}	-20 to +85	$^\circ\text{C}$
Storage temperature	T_{stg}	-40 to +100	$^\circ\text{C}$

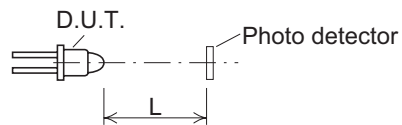
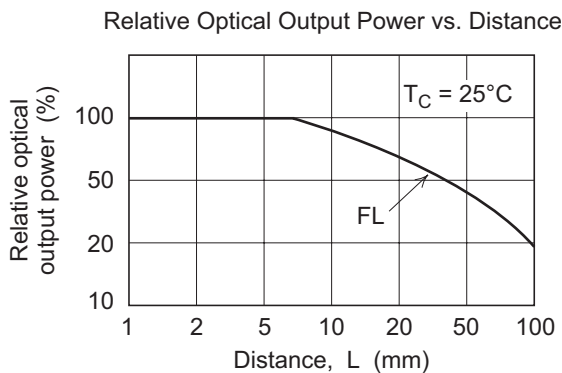
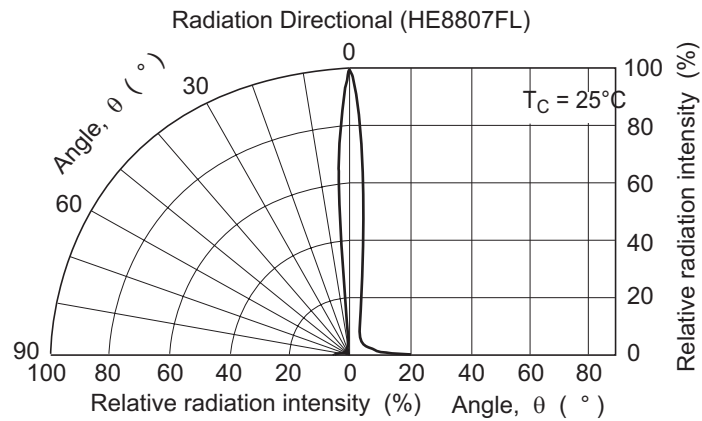
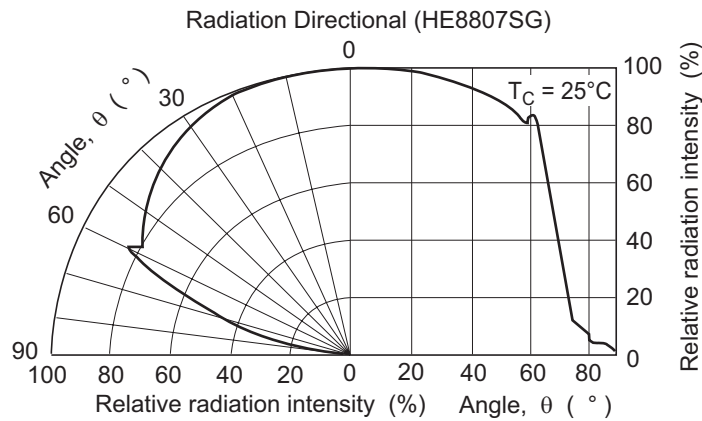
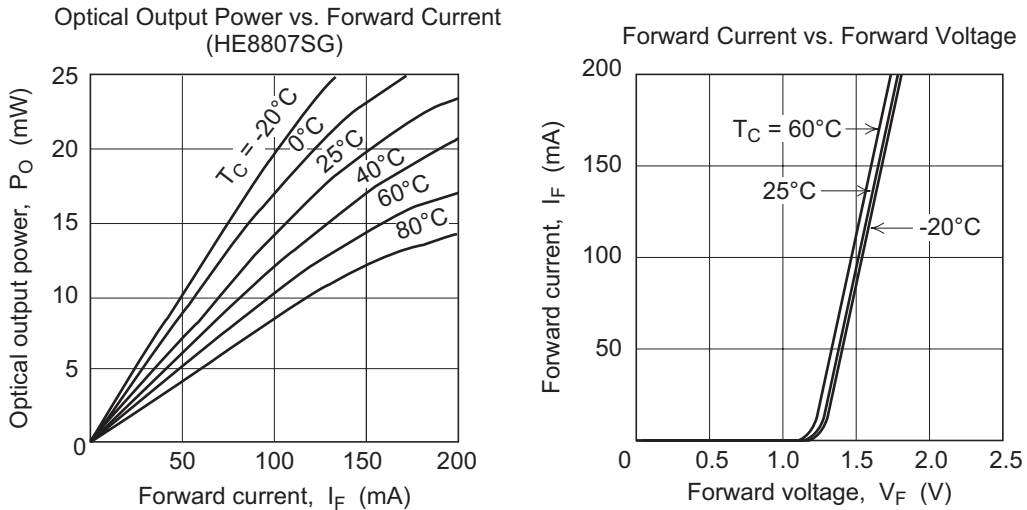
Optical and Electrical Characteristics

($T_C = 25^\circ\text{C}$)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions	
Optical output power	HE8807SG	P_O	10	20	—	mW	$I_F = 150 \text{ mA}$
	HE8807FL	P_f^*	0.5	1.0	—		$I_F = 20 \text{ mA}$
Peak wavelength	λ_p	800	880	900	nm	$I_F = 150 \text{ mA}$	
Spectral width	$\Delta\lambda$	—	30	60	nm	$I_F = 150 \text{ mA}$	
Forward voltage	V_F	—	1.7	2.3	V	$I_F = 150 \text{ mA}$	
Reverse current	I_R	—	—	100	μA	$V_R = 3 \text{ V}$	
Capacitance	C_t	—	10	—	pF	$V_R = 0 \text{ V}, f = 1 \text{ MHz}$	
Rise time	t_r	—	20	—	ns	$I_F = 50 \text{ mA}$	
Fall time	t_f	—	20	—	ns	$I_F = 50 \text{ mA}$	

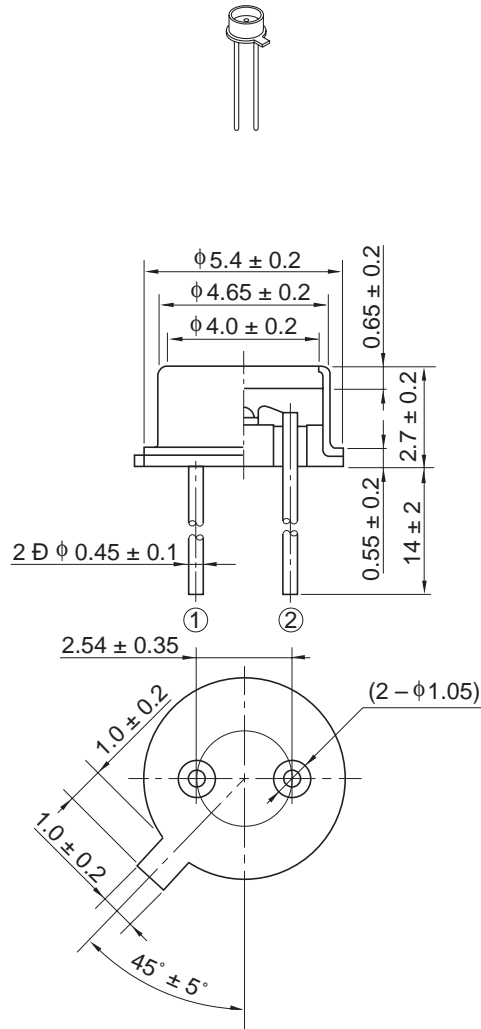
Note: P_f specification: The optical output within 9 degrees of the acceptance angle.

Typical Characteristic Curves



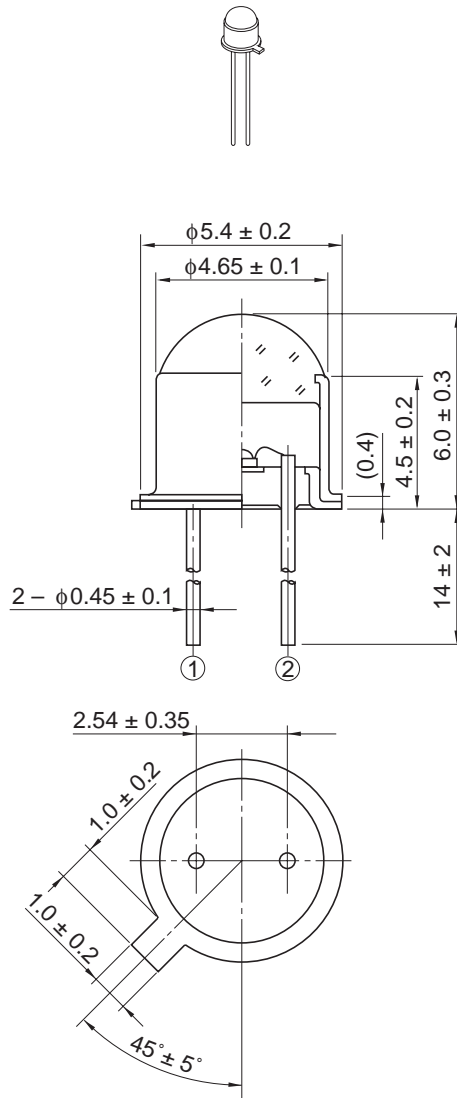
Package Dimensions

As of July, 2002
Unit: mm



OPJ Code	IR/SG1
JEDEC	—
JEITA	—
Mass (reference value)	0.25 g

As of July, 2002
Unit: mm



OPJ Code	IR/FL
JEDEC	—
JEITA	—
Mass (reference value)	0.27 g

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Sales Offices



Device Business Unit Opnext Japan, Inc.

Takagi Bldg., 3F, 1-3-9, Iwamoto-cho, Chiyoda-ku, Tokyo 101-0032 Japan
Tel: (03) 3865-5591

For the detail of Opnext, Inc., see the following homepage:

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